



74LVCH2T45

#### DUAL BIT DUAL POWER SUPPLY TRANSLATING TRANSCEIVER WITH 3 STATE OUTPUTS

#### Description

The 74LVCH2T45 is a dual-bit, dual-supply transceiver with tri-state outputs suitable for transmitting two logic bits across different voltage domains. The direction pin (DIR) and Port A, consisting of pins 1A and 2A, have logic levels in relation to V<sub>CC</sub>(A) while port B, consisting of pins 1B and 2B have logic levels related to V<sub>CC</sub>(B). This arrangement allows for universal low-voltage translation between any voltages from 1.2V to 5.5V. When a HIGH logic level is applied to the direction pin, port A pins become inputs and port B pins are outputs. Conversely, the roles of the ports are reversed when the direction pin is asserted LOW.

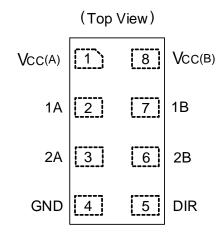
The tri-state (loff) feature places all port pins in a high impedance state when either power supply is at 0V, which prevents and damages backflow currents and provides power-down electrical isolation up to 5.5V as not to interfere with any logic activity on either of the ports.

The 74LVCH2T45 is a variant of the 74LVC2T45 that includes a bus hold feature at each input. The bus hold feature maintains the previous logic level therefore a valid logic level is always present eliminating the need for additional resistors for unused or disconnected inputs.

#### **Features**

- Wide Supply Voltage Range:
  - Vcc(A): from 1.2V to 5.5V
  - Vcc(B): from 1.2V to 5.5V
- ± 24mA Output Drive at 3.3V
- CMOS Low Power Consumption 16µA Maximum Icc
- High Noise Immunity
- IOFF Supports Partial-Power-Down Mode Operation
- I<sub>OFF</sub> Controlled by Either V<sub>CC</sub> Being at 0V
- Inputs Accept up to 5.5V
- Maximum data rates:
  - 420Mbps (3.3V to 5V translation)
  - 210Mbps (translate to 3.3V)
  - 140Mbps (translate to 2.5V)
  - 75Mbps (translate to 1.8V)
  - 60Mbps (translate to 1.5V)
- ESD Protection Exceeds JESD 22
  - 4000-V Human Body Model (A114)
- 1000 V Charged Device Model (C101)
   Latch-up Exceeds 100mA per JESD 78, Class I
- Specified from -40°C to +85°C and -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

### **Pin Assignments**



X2-DFN1210-8 X2-DFN1410-8

### **Applications**

- Voltage Level Translation
   Well-Suited to Join Logic Types Operating at Different Voltages
- Power-Down Signal Isolation
   If Either Voltage Domain is Turned Off the Signal is Isolated and There is No Loading on Signal Lines
- Wide Array of Products, such as:
  - Cell Phones, Tablets, E-Readers
  - PCs, Notebooks, Netbooks, Ultrabooks
  - Networking, Routers, Gateways
  - Computer Peripherals, Hard Drives, CD/DVD ROM
  - TV, DVD, DVR, Set-Top Box
  - Personal Navigation / GPS
  - MP3 Players, Cameras, Video Recorders

Notes:

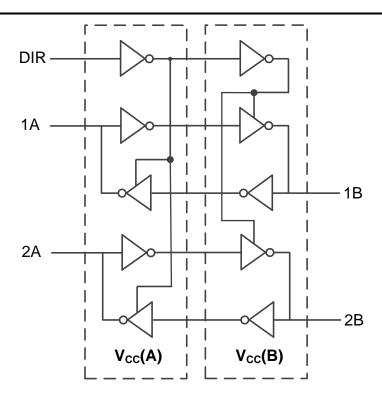
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



### **Pin Descriptions**

Pin Name	Pin	Function
VCC(A)	1	Supply for I/O Pin A; Reference for DIR
1A	2	Data Input/Output
2A	3	Data Input/Output
GND	4	Ground
DIR	5	Direction Control
2B	6	Data Input/Output
1B	7	Data Input/Output
VCC(B)	8	Supply for I/O Pin B

# Logic Diagram



# **Function Tables**

Input DIR (Direction Pin)	Operation
L	B Data to A Output
Н	A Data to B Output

	Inputs		Outputs		
Α	В	DIR	Α	В	
Note 4	L	L	L	Note 4	
Note 4	Н	L	Н	Note 4	
L	Note 4	Н	Note 4	L	
Н	Note 4	Н	Note 4	Н	

Note: 4. Pin condition not applicable as defined by DIR.



### Absolute Maximum Ratings (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter		Rating	Unit
ESD HBM	Human Body Model ESD Protection	4	kV	
ESD CDM	Charged Device Model ESD Protection	1	kV	
V <sub>CC</sub> (A), V <sub>CC</sub> (B)	Supply Voltage Range		-0.5 to +6.5	V
Vı	Input Voltage Range	-0.5 to +6.5	V	
Vo	Voltage Applied to Output in High Impedance or IoF	-0.5 to +6.5	V	
\/ -	Voltage Applied to Output in High or Low State	A Pin	-0.3 to V <sub>CC</sub> (A) +0.5	V
Vo	Voltage Applied to Output in High or Low State	B Pin	-0.3 to Vcc(B) +0.5	V
lıĸ	Input Clamp Current V <sub>I</sub> < 0		-50	mA
Іок	Output Clamp Current		-50	mA
Io	Continuous Output Current		±50	mA
_	Continuous Current Through Vcc or GND	Continuous Current Through Vcc or GND		
TJ	Operating Junction Temperature	-40 to +150	°C	
Tstg	Storage Temperature		-65 to +150	°C

Note:

# Recommended Operating Conditions (Note 6) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc(A)	Supply Voltage A	_	1.2	5.5	V
Vcc(B)	Supply Voltage B	1	1.2	5.5	V
Vı	Input Voltage	I	0	5.5	V
1/0	Output Valtage	Active Mode (Note 6)	0	V <sub>cco</sub>	V
Vo	Output Voltage	Suspend or 3-State Mode	0	5.5	V
$T_A$	Ambient Temperature	ı	-40	+125	°C
		Vcci = 1.2V (Note 7)	_	20	ns/V
		V <sub>CCI</sub> = 1.4V to 1.95V	_	20	ns/V
Δt/ΔV	Input Transition Rise and Fall Rate	Vcci = 2.3V to 2.7V	_	20	ns/V
		V <sub>CCI</sub> = 3V to 3.6V	_	10	ns/V
		V <sub>CCI</sub> = 4.5V to 5.5V	_	5	ns/V

Notes:

<sup>5.</sup> Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

<sup>6.</sup>  $\ensuremath{V_{\text{CCO}}}$  is the supply voltage associated with the output port.

<sup>7.</sup>  $\ensuremath{V_{\text{CCI}}}$  is the supply voltage associated with the input port.



### **Electrical Characteristics** (@TA = +25°C.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OH</sub>	HIGH-Level Output Voltage	VI = VIH or VIL; IO = -3mA; VCCO = 1.2V	1	1.09	_	٧
$V_{OL}$	LOW-Level Output Voltage	$V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 3$ mA; $V_{CCO} = 1.2V$	ı	0.07	_	٧
II	Input Leakage Current	DIR Input; $V_1 = 0V$ to 5.5V; $V_{CC1} = 1.2V$ to 5.5V	ı	_	±1	μΑ
I <sub>BHL</sub>	Bus Hold LOW Current	A or B Port; V <sub>I</sub> = 0.42V; V <sub>CCI</sub> = 1.2V	ı	19	_	μΑ
I <sub>BHH</sub>	Bus Hold HIGH Current	A or B Port; V <sub>I</sub> = 0.78V; V <sub>CCI</sub> = 1.2V	1	19	_	μΑ
I <sub>BHLO</sub>	Bus Hold LOW Overdrive Current	A or B Port; Vcci = 1.2V	ı	19	_	μΑ
I <sub>BHHO</sub>	Bus Hold HIGH Overdrive Current	A or B Port; Vcci = 1.2V	ı	19	_	μΑ
I <sub>OZ</sub>	OFF-State Output Current	A or B Port; $V_0 = 0V$ or $V_{CCO}$ ; $V_{CCO} = 1.2V$ to 5.5V	-	_	±1	μΑ
	Devices Off Leadings Company	A Port; V <sub>I</sub> or V <sub>O</sub> = 0V to 5.5V; V <sub>CC</sub> (A) = 0V; V <sub>CC</sub> (B) = 1.2V to 5.5V	_	_	±1	μΑ
l <sub>OFF</sub>	Power-Off Leakage Current	B Port; $V_1$ or $V_0 = 0V$ to 5.5V; $V_{CC}(B) = 0V$ ; $V_{CC}(A) = 1.2V$ to 5.5V	-	_	±1	μΑ
Сі	Input Capacitance	DIR Input; $V_I = 0V$ or 3.3V; $V_{CC}(A) = V_{CC}(B) = 3.3V$		2.2		pF
C <sub>I/O</sub>	Input/Output Capacitance	A and B Port; Suspend Mode; Vo = 3.3V or 0V; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 3.3V	-	6.0	_	pF

# Electrical Characteristics (continued) (@T<sub>A</sub> = +25°C.)

0	Danamatan	O-milition -	-40°C	to +85°C	-40°C	to +125°C	1114
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
		Data Input					
		Vcci = 1.2V	0.8Vccı	1	0.8Vccı		V
		Vcci = 1.4V to 1.95V	0.65Vccı	_	0.65Vccı		V
		V <sub>CCI</sub> = 2.3V to 2.7V	1.7	_	1.7	_	V
		V <sub>CCI</sub> = 3.0V to 3.6V	2.0	_	2.0	_	V
\/	HIGH-Level	Vcci = 4.5V to 5.5V	0.7Vccı	_	0.7Vccı	_	V
$V_{IH}$	Input Voltage	DIR Input					
		Vcci = 1.2V	0.8V <sub>CC</sub> (A)	_	0.8V <sub>CC</sub> (A)		V
		Vcci = 1.4V to 1.95V	0.65Vcc(A)	_	0.65Vcc(A)		V
		Vcci = 2.3V to 2.7V	1.7	_	1.7		V
		Vcci = 3.0V to 3.6V	2.0	1	2.0		V
		V <sub>CCI</sub> = 4.5V to 5.5V	0.7Vcc(A)	_	0.7Vcc(A)		V
		Data Input					
		Vcci = 1.2V	_	0.2Vccı	_	0.2Vccı	V
\/	LOW-Level Input	V <sub>CCI</sub> = 1.4V to 1.95V	_	0.35V <sub>CCI</sub>	_	0.35V <sub>CCI</sub>	V
$V_{IL}$	Voltage	Vcci = 2.3V to 2.7V	_	0.7	_	0.7	V
		Vcci = 3.0V to 3.6V		0.8	_	0.8	V
		Vcci = 4.5V to 5.5V	_	0.3Vccı	_	0.3Vccı	V



# Electrical Characteristics (continued) (@TA = +25°C.)

	_		-40°C	C to +85°C	-40°C	11	
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
		DIR Input	<b>!</b>			l .	
		Vcci = 1.2V		0.2V <sub>CC</sub> (A)	_	0.2V <sub>CC</sub> (A)	V
V	LOW-Level Input Voltage	Vcci = 1.4V to 1.95V		0.35Vcc(A)	_	0.35Vcc(A)	V
$V_{IL}$		Vcci = 2.3V to 2.7V	_	0.7	_	0.7	V
		V <sub>CCI</sub> = 3.0V to 3.6V	_	0.8	_	0.8	V
		V <sub>CCI</sub> = 4.5V to 5.5V	_	0.3Vcc(A)	1	0.3Vcc(A)	V
		$V_I = V_{IH}$					
		I <sub>O</sub> = -100μA V <sub>CCO</sub> = 1.2V to 4.5V	Vcco - 0.1	_	Vcco - 0.1	_	V
	HIGH-Level	Io = -6mA; Vcco = 1.4V	1.0	_	1.0	_	V
$V_{OH}$	Output Voltage	Io = -8mA; Vcco = 1.65V	1.2	_	1.2	_	V
		Io = -12mA; Vcco = 2.3V	1.9	_	1.9	_	V
		Io = -24mA; Vcco = 3.0V	2.4	_	2.4	_	V
		Io = -32mA; Vcco = 4.5V	3.8	_	3.8	_	V
	LOW-Level Output Voltage	$V_I = V_{IL}$					
		I <sub>O</sub> = 100μA; V <sub>CCO</sub> = 1.2V to 4.5V	_	0.1	_	0.1	٧
		Io = 6mA; Vcco = 1.4V	_	0.3	1	0.3	V
$V_{OL}$		I <sub>O</sub> = 8mA; V <sub>CCO</sub> = 1.65V	_	0.45	1	0.45	V
		$I_{O} = 12mA; V_{CCO} = 2.3V$	_	0.3	1	0.3	V
		Io = 24mA; Vcco = 3.0V	_	0.55	_	0.55	V
		Io = 32mA; Vcco = 4.5V	_	0.55	_	0.55	V
lı	Input Leakage Current	DIR Input; $V_I = 0V$ to 5.5V; $V_{CCI} = 1.2V$ to 5.5V	_	±2	_	±10	μA
l <sub>OZ</sub>	OFF-State Output Current	A or B Port; Vo = 0V or Vcco; Vcco = 1.2V to 5.5V	_	±2		±10	μA
		A or B Port					
		V <sub>I</sub> = 0.49V; V <sub>CCI</sub> = 1.4V	15	_	10	_	μA
1	Bus Hold LOW	V <sub>I</sub> = 0.58V; V <sub>CCI</sub> = 1.65V	25	_	20	_	μA
I <sub>BHL</sub>	Current	V <sub>I</sub> = 0.70V; V <sub>CCI</sub> = 2.3V	45	_	45	_	μA
		V <sub>I</sub> = 0.80V; V <sub>CCI</sub> = 3.0V	100	_	80	_	μA
		V <sub>I</sub> = 1.35V; V <sub>CCI</sub> = 4.5V	100	_	100	_	μA
		A or B Port	1			l	
		V <sub>I</sub> = 0.91V; V <sub>CCI</sub> = 1.4V	-15	_	-10	_	μΑ
l	Bus Hold HIGH	Id HIGH V <sub>I</sub> = 1.07V; V <sub>CCI</sub> = 1.65V			-20		μΑ
I <sub>BHH</sub>	Current	V <sub>I</sub> = 1.60V; V <sub>CCI</sub> = 2.3V	-45	_	-45	_	μΑ
		V <sub>I</sub> = 2.00V; V <sub>CCI</sub> = 3.0V	-100	_	-80	_	μΑ
		V <sub>I</sub> = 3.15V; V <sub>CCI</sub> = 4.5V	-100	_	-100	_	μA



# Electrical Characteristics (continued) (@TA = +25°C.)

Complete	Donomoton	Conditions	-40°C	C to +85°C	-40°C to +125°C		11:4
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
		A or B Port					
		Vcci = 1.6V	125	_	125	_	μА
	Bus Hold LOW	Vcci = 1.95V	200	_	200	_	μA
I <sub>BHLO</sub>	Overdrive Current	Vcci = 2.7V	300	_	300	_	μA
		V <sub>CCI</sub> = 3.6V	500	_	500	_	μА
		V <sub>CCI</sub> = 5.5V	900	_	900	_	μΑ
		A or B port	I	I			
		Vcci = 1.6V	-125	_	-125	_	μΑ
1	Bus Hold HIGH	V <sub>CCI</sub> = 1.95V	-200	_	-200	_	μA
I <sub>BHHO</sub>	Overdrive Current	V <sub>CCI</sub> = 2.7V	-300	_	-300	_	μA
		Vcci = 3.6V	-500	_	-500	_	μA
		V <sub>CCI</sub> = 5.5V	-900	_	-900	_	μA
	Power-Off Leakage	A Port; $V_1$ or $V_0 = 0V$ to 5.5V; $V_{CC}(A) = 0V$ ; $V_{CC}(B) = 1.2V$ to 5.5V	_	±2	_	±10	μΑ
loff	Current	B Port; $V_1$ or $V_0 = 0V$ to 5.5V; $V_{CC}(B) = 0V$ ; $V_{CC}(A) = 1.2V$ to 5.5V	_	±2	_	±10	μΑ
		A Port; $V_I = 0V$ or $V_{CCI}$ ; $I_O = 0A$	_	_	_	_	<u> </u>
		$V_{CC}(A)$ , $V_{CC}(B) = 1.2V$ to 5.5V	_	8	_	8	μΑ
		$V_{CC}(A)$ , $V_{CC}(B) = 1.65V$ to 5.5V		3	_	3	μΑ
		V <sub>CC</sub> (A) = 5.5V ; V <sub>CC</sub> (B) = 0V	_	2	_	2	μΑ
		$V_{CC}(A) = 0V ; V_{CC}(B) = 5.5V$	-2	_	-2	_	μA
		B Port; VI = 0V or Vcci; Io = 0A	_	_	_		
Icc	Supply Current	$V_{CC}(A)$ , $V_{CC}(B) = 1.2V$ to 5.5V	_	8	_	8	μA
		$V_{CC}(A)$ , $V_{CC}(B) = 1.65V$ to 5.5V	_	3	_	3	μA
		$V_{CC}(A) = 5.5V ; V_{CC}(B) = 0V$	-2	_	-2	_	μA
		Vcc(A) = 0V ; Vcc(B) = 5.5V	_	2	_	2	μA
		A Plus B Port ( $I_{CC(A)} + I_{CC(B)}$ ); $I_0 = 0A$ ; $V_1 = 0V$ or $V_{CC1}$	_	_		_	_
		$V_{CC}(A)$ , $V_{CC}(B) = 1.2V$ to 5.5V	_	16	_	16	μA
		$V_{CC}(A)$ , $V_{CC}(B) = 1.65V$ to 5.5V	_	4	_	4	μA



### Package Characteristics (V<sub>CC</sub> = 3.3V, T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
$\Delta_{1\lambda}$	Thermal Resistance Junction-	X2-DFN1210-8	Note 0	_	295	-	°C/W
	to-Ambient	X2-DFN1410-8	Note 8	_	133	_	
0	Thermal Resistance Junction-	X2-DFN1210-8	Note 8	_	280	_	°C/W
Өлс	to-Case	X2-DFN1410-8	Note o	-	127		

Note: 8. Test condition for X2- DFN1210-8 and X2- DFN1410-8: Device mounted on FR-4 substrate PCB, 2oz copper with minimum recommended pad layout.

# **Switching Characteristics** ( $V_{CC}$ (A) = 1.2V, $T_A$ = +25°C, see Figure 1)

Parameter	From	То	Vcc(B) = 1.2V	Vcc(B) = 1.5V	Vcc(B) = 1.8V	Vcc(B) = 2.5V	Vcc(B) = 3.3V	Vcc(B) = 5V	Unit
rarameter	(Input)	(Output)	Тур	Тур	Тур	Тур	Тур	Тур	Oilit
4	Α	В	10.6	8.1	7.0	5.8	5.3	5.1	no
t <sub>pLH</sub>	В	Α	10.6	9.5	9.0	8.5	8.3	8.2	ns
4	Α	В	10.1	7.1	6.0	5.3	5.2	5.4	no
t <sub>pHL</sub>	В	Α	10.1	8.6	8.1	7.8	7.6	7.6	ns
	DIR	Α	9.4	9.4	9.4	9.4	9.4	9.4	ns
t <sub>pHZ</sub>	DIR	В	12.0	9.4	9.0	7.8	8.4	7.9	
	DIR	Α	7.1	7.1	7.1	7.1	7.1	7.1	
t <sub>pLZ</sub>	DIR	В	9.5	7.8	7.7	6.9	7.6	7.0	ns
	DIR	Α	20.1	17.3	16.7	15.4	15.9	15.2	
t <sub>p</sub> zH	DIR	В	17.7	15.2	14.1	12.9	12.4	12.2	ns
4	DIR	Α	22.1	18.0	17.1	15.6	16.0	15.5	
tpZL	DIR	В	19.5	16.5	15.4	14.7	14.6	14.8	ns



# Switching Characteristics (Vcc (B) = 1.2V, TA = 25°C, see Figure 1)

Parameter	From	То	Vcc(A) = 1.2V	Vcc(A) = 1.5V	Vcc(A) = 1.8V	Vcc(A) = 2.5V	Vcc(A) = 3.3V	Vcc(A) = 5V	Unit
Farameter	(Input)	(Output)	Тур	Тур	Тур	Тур	Тур	Тур	Oilit
4	Α	В	10.6	9.5	9.0	8.5	8.3	8.2	20
t <sub>pLH</sub>	В	Α	10.6	8.1	7.0	5.8	5.3	5.1	ns
	Α	В	10.1	8.6	8.1	7.8	7.6	7.6	ns
t <sub>pHL</sub>	В	Α	10.1	7.1	6.0	5.3	5.2	5.4	
4	DIR	Α	9.4	6.5	5.7	4.1	4.1	3.0	ns
t <sub>pHZ</sub>	DIR	В	12.0	6.1	5.4	4.6	4.3	4.0	
4	DIR	Α	7.1	4.9	4.5	3.2	3.4	2.5	no
t <sub>pLZ</sub>	DIR	В	9.5	7.3	6.6	5.9	5.7	5.6	ns
4	DIR	Α	20.1	15.4	13.6	11.7	11.0	10.7	
<b>t</b> pZH	DIR	В	17.7	14.4	13.5	11.7	11.7	10.7	ns
4	DIR	Α	22.1	13.2	11.4	9.9	9.5	9.4	20
tpZL	DIR	В	19.5	15.1	13.8	11.9	11.7	10.6	ns

# **Switching Characteristics** ( $V_{CC}$ (A) = 1.5V $\pm$ 0.1V, $T_A$ = -40°C to +85°C, see Figure 1)

Parameter	From (Input)	To (Output)		= 1.5V .1V		) = 1.8V .15V	•	) = 2.5V 0.2V		) = 3.3V ).3V		3) = 5V ).5V	Unit
	(iliput)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
4	Α	В	2.8	21.3	2.4	17.6	2.0	13.5	1.7	11.8	1.6	10.5	no
t <sub>pLH</sub>	В	Α	2.8	21.3	2.6	19.1	2.3	14.9	2.3	12.4	2.2	12.0	ns
	Α	В	2.6	19.3	2.2	15.3	1.8	11.8	1.7	10.9	1.7	10.8	
t <sub>pHL</sub>	В	Α	2.6	19.3	2.4	17.3	2.3	13.2	2.2	11.3	2.3	11.0	ns
	DIR	Α	3.0	18.7	3.0	18.7	3.0	18.7	3.0	18.7	3.0	18.7	20
t <sub>pHZ</sub>	DIR	В	3.5	24.8	3.5	23.6	3.0	11.0	3.3	11.3	2.8	10.3	ns
	DIR	Α	2.4	11.4	2.4	11.4	2.4	11.4	2.4	11.4	2.4	11.4	no
t <sub>pLZ</sub>	DIR	В	2.8	18.3	3.0	17.2	2.5	9.4	3.0	10.1	2.5	9.4	ns
	DIR	Α	_	39.6	_	36.3	_	24.3	_	22.5	_	21.4	
tpZH	DIR	В	_	32.7	_	29.0	_	24.9	_	23.2	_	21.9	ns
4	DIR	Α		44.1	_	40.9	_	24.2	_	22.6	_	21.3	20
tpZL	DIR	В	_	38.0	_	34.0	_	30.5	_	29.6	_	29.5	ns

# **Switching Characteristics** (continued) ( $V_{CC}$ (A) = 1.8V $\pm$ 0.15V, $T_A$ = -40°C to +85°C, see Figure 1)

Parameter	From (Input)	To (Output)		= 1.5V .1V		) = 1.8V .15V		) = 2.5V 0.2V		) = 3.3V ).3V		3) = 5V 0.5V	Unit
	(Iliput)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
4	А	В	2.6	19.1	2.2	17.7	2.2	9.3	1.7	7.2	1.4	6.8	20
t <sub>pLH</sub>	В	Α	2.4	17.6	2.2	17.7	2.3	16.0	2.1	15.5	1.9	15.1	ns
4	А	В	2.4	17.3	2.0	14.3	1.6	8.5	1.8	7.1	1.7	7.0	ns
t <sub>pHL</sub>	В	Α	2.2	15.3	2.0	14.3	2.1	12.9	2.0	12.6	1.8	12.2	115
t	DIR	Α	2.9	17.1	2.9	17.1	2.9	17.1	2.9	17.1	2.9	17.1	20
t <sub>pHZ</sub>	DIR	В	3.2	24.1	3.2	21.9	2.7	11.5	3.0	10.3	2.5	8.2	ns
4	DIR	Α	2.4	10.5	2.4	10.5	2.4	10.5	2.4	10.5	2.4	10.5	20
t <sub>pLZ</sub>	DIR	В	2.5	17.6	2.6	16.0	2.2	9.2	2.7	8.4	2.4	7.1	ns
4	DIR	Α	_	35.2	_	33.7	_	25.2	_	23.9	_	22.2	20
t <sub>р</sub> ZН	DIR	В	_	29.6	_	28.2	_	19.8	_	17.7	_	17.3	ns
4	DIR	Α	_	39.4	_	36.2	_	24.4	_	22.9	_	20.4	20
t <sub>pZL</sub>	DIR	В	_	34.4	_	31.4	_	25.6	_	24.2	_	24.1	ns



# **Switching Characteristics** (continued) ( $V_{CC}$ (A) = 2.5V $\pm$ 0.2V, $T_{A}$ = -40°C to +85°C, see Figure 1)

Parameter	From (Input)	To (Output)		= 1.5V .1V		) = 1.8V .15V	•	) = 2.5V 0.2V	` '	) = 3.3V ).3V		3) = 5V 0.5V	Unit
	(IIIput)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
4	А	В	2.3	17.9	2.3	16.0	1.5	8.5	1.3	6.2	1.1	4.8	20
t <sub>pLH</sub>	В	Α	2.0	13.5	2.2	9.3	1.5	8.5	1.4	8.0	1.0	7.5	ns
4	А	В	2.3	15.8	2.1	12.9	1.4	7.5	1.3	5.4	0.9	4.6	
t <sub>pHL</sub>	В	Α	1.8	11.8	1.9	8.5	1.4	7.5	1.3	7.0	0.9	6.2	ns
	DIR	Α	2.1	8.1	2.1	8.1	2.1	8.1	2.1	8.1	2.1	8.1	
t <sub>pHZ</sub>	DIR	В	3.0	22.5	3.0	21.4	2.5	11.0	2.8	9.3	2.3	6.9	ns
4	DIR	Α	1.7	5.8	1.7	5.8	1.7	5.8	1.7	5.8	1.7	5.8	
t <sub>pLZ</sub>	DIR	В	2.3	14.6	2.5	13.2	2.0	9.0	2.5	8.4	1.8	5.8	ns
	DIR	Α	_	28.1	_	22.5	_	17.5	_	16.4	_	13.3	
t <sub>p</sub> zH	DIR	В	_	23.7	_	21.8	_	14.3	_	12.0	_	10.6	ns
4	DIR	Α	_	34.3	_	29.9	_	18.5	_	16.3	_	13.1	
t <sub>pZL</sub>	DIR	В	_	23.9	_	21.0	_	15.6	_	13.5	_	12.7	ns

# **Switching Characteristics** (continued) ( $V_{CC}$ (A) = 3.3V ± 0.3V, $T_{A}$ = -40°C to +85°C, see Figure 1)

Parameter	From (Input)	To (Output)		= 1.5V .1V		) = 1.8V .15V		) = 2.5V 0.2V		) = 3.3V ).3V		3) = 5V 0.5V	Unit
	(iliput)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
4	Α	В	2.3	17.1	2.1	15.5	1.4	8.0	0.8	5.6	0.7	4.4	no
t <sub>pLH</sub>	В	Α	1.7	11.8	1.7	7.2	1.3	6.2	0.7	5.6	0.6	5.4	ns
4	Α	В	2.2	15.6	2.0	12.6	1.3	7.0	0.8	5.0	0.7	4.0	
t <sub>pHL</sub>	В	Α	1.7	10.9	1.8	7.1	1.3	5.4	0.8	5.0	0.7	4.5	ns
4	DIR	Α	2.3	7.3	2.3	7.3	2.3	7.3	2.3	7.3	2.7	7.3	
t <sub>pHZ</sub>	DIR	В	2.9	18.0	2.9	16.5	2.3	10.1	2.7	8.6	2.2	6.3	ns
	DIR	Α	2.0	5.6	2.0	5.6	2.0	5.6	2.0	5.6	2.0	5.6	
t <sub>pLZ</sub>	DIR	В	2.3	13.6	2.4	12.5	1.9	7.8	2.3	7.1	1.7	4.9	ns
	DIR	Α	_	25.4	_	19.7	_	14.0	_	12.7	_	10.3	
t <sub>pZH</sub>	DIR	В	_	22.7	_	21.1	_	13.6	_	11.2	_	10.0	ns
	DIR	Α	_	28.9	_	23.6	_	15.5	_	13.6	_	10.8	
<b>t</b> pZL	DIR	В	_	22.9	_	19.9	_	14.3	_	12.3	_	11.3	ns

### **Switching Characteristics** (continued) ( $V_{CC}$ (A) = 5.0V ± 0.5V, $T_{A}$ = -40°C to +85°C, see Figure 1)

Parameter	From (Input)	To (Output)		= 1.5V .1V		) = 1.8V .15V		) = 2.5V 0.2V		) = 3.3V ).3V		3) = 5V 3.5V	Unit
	(iliput)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
	Α	В	2.2	16.6	1.9	15.1	1.0	7.5	0.7	5.4	0.5	3.9	20
t <sub>pLH</sub>	В	Α	1.6	10.5	1.4	6.8	1.0	4.8	0.7	4.4	0.5	3.9	ns
	Α	В	2.3	15.3	1.8	12.2	1.0	6.2	0.7	4.5	0.5	3.5	20
t <sub>pHL</sub>	В	Α	1.7	10.8	1.7	7.0	0.9	4.6	0.7	4.0	0.5	3.5	ns
4	DIR	Α	1.7	5.4	1.7	5.4	1.7	5.4	1.7	5.4	1.7	5.4	20
t <sub>pHZ</sub>	DIR	В	2.9	17.3	2.9	16.1	2.3	9.7	2.7	8.0	2.5	5.7	ns
4	DIR	Α	1.4	3.7	1.4	3.7	1.3	3.7	1.0	3.7	0.9	3.7	20
t <sub>pLZ</sub>	DIR	В	2.3	13.1	2.4	12.1	1.9	7.4	2.3	7.0	1.8	4.5	ns
	DIR	Α	_	23.6	_	18.9	_	12.2	_	11.4	_	8.4	20
t <sub>pZH</sub>	DIR	В	_	20.3	_	18.8	_	11.2	_	9.1	_	7.6	ns
4	DIR	Α	_	28.1	_	23.1	_	14.3	_	12.0	_	9.2	20
<b>t</b> pZL	DIR	В	_	20.7	_	17.6	_	11.6	_	9.9	_	8.9	ns



### **Switching Characteristics** (continued) ( $V_{CC}$ (A) = 1.5V ± 0.1V, $T_A$ = -40°C to +125°C, see Figure 1)

Parameter	From (Input)	To (Output)		= 1.5V .1V		) = 1.8V .15V	•	) = 2.5V 0.2V		) = 3.3V ).3V		3) = 5V ).5V	Unit
	(iliput)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
<b></b>	Α	В	2.5	23.5	2.1	19.4	1.8	14.9	1.5	13.0	1.4	11.6	nc
t <sub>pLH</sub>	В	Α	2.5	23.5	2.3	21.1	2.0	16.4	2.0	13.7	1.9	13.2	ns
4	Α	В	2.3	21.3	1.9	16.9	1.6	13.0	1.5	12.0	1.5	11.9	
t <sub>pHL</sub>	В	Α	2.3	21.3	2.1	19.1	2.0	14.6	1.9	12.5	2.0	12.1	ns
t=117	DIR	Α	2.7	20.6	2.7	20.6	2.7	20.6	2.7	20.6	2.7	20.6	
t <sub>pHZ</sub>	DIR	В	3.1	27.3	3.1	26.0	2.7	12.1	2.9	12.5	2.5	11.4	ns
4	DIR	Α	2.1	12.6	2.1	12.6	2.1	12.6	2.1	12.6	2.1	12.6	ns
t <sub>pLZ</sub>	DIR	В	2.5	20.2	2.7	19.0	2.2	10.4	2.7	11.2	2.2	10.4	115
4	DIR	Α	_	43.7	_	40.1	_	26.8	_	24.9	_	23.6	
t <sub>pZH</sub>	DIR	В	_	36.1	_	32.0	_	27.5	_	25.6	_	24.2	ns
4	DIR	Α	_	48.6	_	45.1	_	26.7	_	25.0	_	23.5	200
t <sub>pZL</sub>	DIR	В	_	41.9	_	37.5	_	33.6	_	32.6	_	32.5	ns

### **Switching Characteristics** (continued) ( $V_{CC}$ (A) = 1.8V $\pm$ 0.15V, $T_A$ = -40°C to +125°C, see Figure 1)

Parameter	From (Input)	To (Output)		= 1.5V .1V		) = 1.8V .15V		) = 2.5V 0.2V	, ,	) = 3.3V ).3V		3) = 5V 3.5V	Unit
	(iliput)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
4	Α	В	2.3	21.1	1.9	19.5	1.9	10.3	1.5	8.0	1.2	7.5	ns
t <sub>pLH</sub>	В	Α	2.1	19.4	1.9	19.5	2.0	17.6	1.8	17.1	1.7	16.7	115
	Α	В	2.1	19.1	1.8	15.8	1.4	9.4	1.6	7.9	1.5	7.7	20
tpHL	В	Α	1.9	16.9	1.8	15.8	1.8	14.2	1.8	13.9	1.6	13.5	ns
t-117	DIR	Α	2.6	18.9	2.6	18.9	2.6	18.9	2.6	18.9	2.6	18.9	ns
t <sub>pHZ</sub>	DIR	В	2.8	26.6	2.8	24.1	2.4	12.7	2.7	11.4	2.2	9.1	115
4	DIR	Α	2.1	11.6	2.1	11.6	2.1	11.6	2.1	11.6	2.1	11.6	20
t <sub>pLZ</sub>	DIR	В	2.2	19.4	2.3	17.6	1.9	10.2	2.4	9.3	2.1	7.9	ns
4	DIR	Α	_	38.8	_	37.1	_	27.8	_	26.4	_	24.6	20
t <sub>р</sub> zн	DIR	В	_	32.7	_	31.1	_	21.9	_	19.6	_	19.1	ns
4	DIR	Α	_	43.5	_	39.9	_	26.9	_	25.3	_	22.6	no
t <sub>pZL</sub>	DIR	В	_	38.0	_	34.7		28.3	_	26.8	_	26.6	ns

### **Switching Characteristics** (continued) (VCC (A) = 2.5V $\pm$ 0.2V, TA = -40°C to +125°C, see Figure 1)

Parameter	From (Input)	To (Output)		= 1.5V .1V		) = 1.8V .15V	•	) = 2.5V 0.2V		) = 3.3V ).3V		3) = 5V 3.5V	Unit
	(iliput)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
4	Α	В	2.0	19.7	2.0	17.6	1.3	9.4	1.1	6.9	0.9	5.3	20
t <sub>pLH</sub>	В	Α	1.8	14.9	1.9	10.3	1.3	9.4	1.2	8.8	0.9	8.3	ns
4	Α	В	2.0	17.4	1.8	14.2	1.2	8.3	1.1	6.0	0.8	5.1	
t <sub>pHL</sub>	В	Α	1.6	13.0	1.7	9.4	1.2	8.3	1.1	7.7	0.8	6.9	ns
4	DIR	Α	1.8	9.0	1.8	9.0	1.8	9.0	1.8	9.0	1.8	9.0	20
t <sub>pHZ</sub>	DIR	В	2.7	24.8	2.7	23.6	2.2	12.1	2.5	10.3	2.0	7.6	ns
4	DIR	Α	1.5	6.4	1.5	6.4	1.5	6.4	1.5	6.4	1.5	6.4	no
t <sub>pLZ</sub>	DIR	В	2.0	16.1	2.2	14.6	1.8	9.9	2.2	9.3	1.6	6.4	ns
4	DIR	Α	_	31.0	_	24.9	_	19.3	_	18.1	_	14.7	20
t <sub>pZH</sub>	DIR	В	_	26.1	_	24.0	_	15.8	_	13.3	_	11.7	ns
4	DIR	Α	_	37.8	_	33.0	_	20.4	_	18.0	_	14.5	no
t <sub>pZL</sub>	DIR	В	_	26.4	_	23.2	_	17.3	_	15.0	_	14.1	ns



### **Switching Characteristics** (continued) (VCC (A) = 3.3V $\pm$ 0.3V, TA = -40°C to +125°C, see Figure 1)

Parameter	From (Input)	To (Output)		= 1.5V .1V		) = 1.8V .15V		) = 2.5V 0.2V		) = 3.3V ).3V		3) = 5V ).5V	Unit
	(Iliput)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
4	Α	В	2.0	18.9	1.8	17.1	1.2	8.8	0.7	6.2	0.6	4.9	ns
t <sub>pLH</sub>	В	Α	1.5	13.0	1.5	8.0	1.1	6.9	0.6	6.2	0.5	6.0	115
4	Α	В	1.9	17.2	1.8	13.9	1.1	7.7	0.7	5.5	0.6	4.4	20
t <sub>pHL</sub>	В	Α	1.5	12.0	1.6	7.9	1.1	6.0	0.7	5.5	0.6	5.0	ns
4	DIR	Α	2.0	8.1	2.0	8.1	2.0	8.1	2.0	8.1	2.4	8.1	20
t <sub>pHZ</sub>	DIR	В	2.6	19.8	2.6	18.2	2.0	11.2	2.4	9.5	1.9	7.0	ns
4	DIR	Α	1.8	6.2	1.8	6.2	1.8	6.2	1.8	6.2	1.8	6.2	ns
t <sub>pLZ</sub>	DIR	В	2.0	15.0	2.1	13.8	1.7	8.6	2.0	7.9	1.5	5.4	115
4	DIR	Α	_	28.0	_	21.8	_	15.5	_	14.1	_	11.4	20
tpZH	DIR	В	_	25.1	_	23.3	_	15.0	_	12.4	_	11.1	ns
4	DIR	Α	_	31.8	_	26.1	_	17.2	_	15.0	_	12.0	no
t <sub>pZL</sub>	DIR	В	_	25.3	_	22.0	_	15.8	_	13.6	_	12.5	ns

### **Switching Characteristics** (continued) ( $V_{CC}$ (A) = 5.0V ± 0.5V, $T_A$ = -40°C to +125°C, see Figure 1)

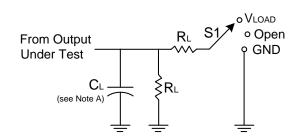
Parameter	From (Input)	To (Output)		= 1.5V .1V		) = 1.8V .15V		) = 2.5V 0.2V	, ,	) = 3.3V ).3V		3) = 5V 3.5V	Unit
	(iliput)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
4	Α	В	1.9	18.3	1.7	16.7	0.9	8.3	0.6	6.0	0.4	4.3	ns
t <sub>pLH</sub>	В	Α	1.4	11.6	1.2	7.5	0.9	5.3	0.6	4.9	0.4	4.3	115
4	Α	В	2.0	16.9	1.6	13.5	0.9	6.9	0.6	5.0	0.4	3.9	20
tpHL	В	Α	1.5	11.9	1.5	7.7	0.8	5.1	0.6	4.4	0.4	3.9	ns
t-117	DIR	Α	1.5	6.0	1.5	6.0	1.5	6.0	1.5	6.0	1.5	6.0	20
t <sub>pHZ</sub>	DIR	В	2.6	19.1	2.6	17.8	2.0	10.7	2.4	8.8	2.2	6.3	ns
4	DIR	Α	1.2	4.1	1.2	4.1	1.1	4.1	0.9	4.1	0.8	4.1	20
t <sub>pLZ</sub>	DIR	В	2.0	14.5	2.1	13.4	1.7	8.2	2.0	7.7	1.6	5.0	ns
4	DIR	Α	_	26.1	_	20.9	_	13.5	_	12.6	_	9.3	20
t <sub>р</sub> zн	DIR	В	_	22.4	_	20.8	_	12.4	_	10.1	_	8.4	ns
4	DIR	Α	_	31.0	_	25.5	_	15.8	_	13.2	_	10.2	no
t <sub>pZL</sub>	DIR	В	_	22.9	_	19.5		12.9	_	11.0	_	9.9	ns

# **Operating Characteristics** (T<sub>A</sub> = +25°C, unless otherwise specified.)

Power Dis	Parameter sipation Capacitance	Test Conditions	Vcc(A) = Vcc(B) = 1.8V Typ	Vcc(A) = Vcc(B) = 2.5V Typ	Vcc(A) = Vcc(B) = 3.3V Typ	Vcc(A) = Vcc(B) = 5V Typ	Unit
	A- Input, B- Output	$C_L = 0pF$	3	4	4	4	
C <sub>pd</sub> (A)	B- Input, A- Output	f = 10MHz $t_R = t_F = 1ns$	18	19	20	21	pF
	A- Input, B- Output	$C_L = 0pF$	18	19	20	21	
C <sub>pd</sub> (B)	B- Input, A- Output	f = 10MHz $t_R = t_F = 1ns$	3	4	4	4	pF

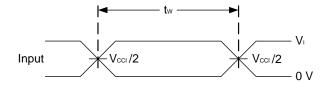


#### **Parameter Measurement Information**

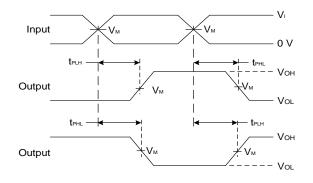


TEST	S1
tplh/tphl	Open
tplz/tpzL	Vload
tpHz/tpzH	GND

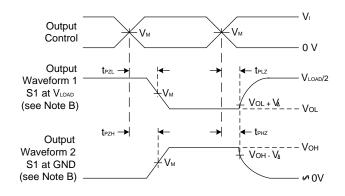
V	Inputs		Ver	Visco	0.	D.	
Vcc	Vı	t <sub>R</sub> /t <sub>F</sub>	VM	VLOAD	CL	R∟	<b>V</b> Δ
1.8V±0.15V	Vccı	≤2ns	Vcco/2	2 X V <sub>CCO</sub>	15pF	2ΚΩ	0.15V
2.5V±0.2V	Vcc	≤2ns	Vcco/2	2 X V <sub>CCO</sub>	15pF	2ΚΩ	0.15V
3.3V±0.3V	3V	≤2.5ns	V <sub>CCO</sub> /2	2 X V <sub>CCO</sub>	15pF	2ΚΩ	0.3V
5V±0.5V	Vcc	≤2.5ns	V <sub>CCO</sub> /2	2 X V <sub>CCO</sub>	15pF	2ΚΩ	0.3V



#### **Voltage Waveform Pulse Duration**



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times Low and High Level Enabling

#### Figure 1 Load Circuit and Voltage Waveforms

Notes: 9. Includes test lead and test apparatus capacitance.

10. Waveform 1 is for an output with input set up as a low and device coming out or into 3-state via DIR control. Waveform 2 is for an output with input set up as a high and device coming out or into 3-state via DIR control.

11. All pulses are supplied at pulse repetition rate ≤ 10 MHz.

12.  $t_{\text{PLZ}}$  and  $t_{\text{PHZ}}$  are the same as  $t_{\text{dis}}$ .

13.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{EN}$ .

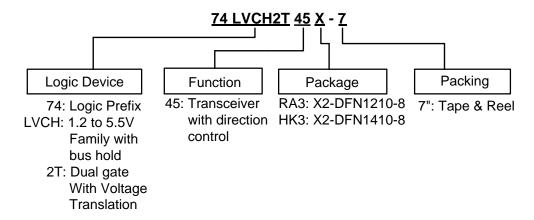
14. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>PD</sub>.

15.  $V_{\text{CCI}}$  is the  $V_{\text{CC}}$  associated with the input.

16.  $V_{\text{CCO}}$  is the  $V_{\text{CC}}$  associated with the output.



#### **Ordering Information**



Part Number	Dookses Code	Dookoaina	7" Tape and	7" Tape and Reel (Note 7)	
Part Number	Package Code	Packaging	Quantity	Part Number Suffix	
74LVCH2T45RA3-7	RA3	X2-DFN1210-8	5000/Tape & Reel	-7	
74LVCH2T45HK3-7	HK3	X2-DFN1410-8	5000/Tape & Reel	-7	

Note: 17. The taping orientation is located on our website at http://www.diodes.com/package-outlines.html.

### **Marking Information**

#### (1) X2-DFN1210-8

#### (Top View)

XX  $\underline{Y} \underline{W} \underline{X}$  XX: Identification Code

Y: Year: 0~9

<u>W</u>: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents

52 and 53 week

X: Internal Code

Part Number	Package	Identification Code	
74LVCH2T45RA3-7	X2-DFN1210-8	4C	

#### (2) X2-DFN1410-8

#### (Top View)



XX: Identification Code

Y: Year: 0~9

<u>W</u>: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents

52 and 53 week X: Internal Code

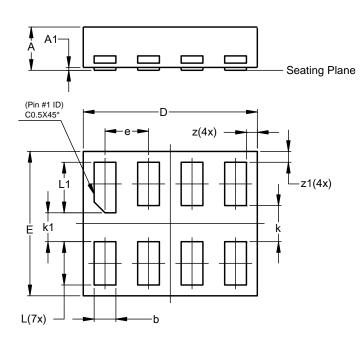
Part Number	Package	Identification Code
74LVCH2T45HK3-7	X2-DFN1410-8	4D



### **Package Outline Dimensions**

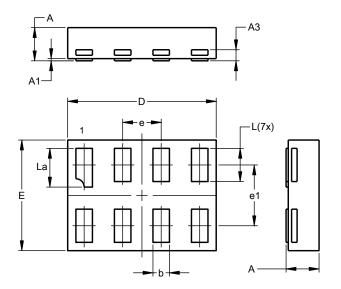
Please see http://www.diodes.com/package-outlines.html for the latest version.

#### X2-DFN1210-8



X2-DFN1210-8			
Dim	Min	Max	Тур
Α	-	0.35	0.30
A1	0	0.03	0.02
b	0.10	0.20	0.15
D	1.15	1.25	1.20
Е	0.95	1.05	1.00
е	-	-	0.30
k	-	-	0.25
k1	-	-	0.20
١	0.25	0.35	0.30
L1	0.30	0.40	0.35
Z	0.050	0.100	0.075
z1	0.050	0.100	0.075
All Dimensions in mm			

#### X2-DFN1410-8



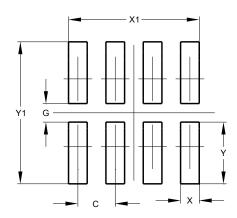
X2-DFN1410-8				
Dim	Min	Max	Тур	
Α	0.30	0.35	0.33	
A1	0.00	0.03	0.02	
A3			0.10	
b	0.12	0.20	0.15	
D	1.30	1.40	1.35	
Е	0.95	1.05	1.00	
е			0.35	
e1			0.55	
L	0.27	0.35	0.30	
L1	0.32	0.40	0.35	
All Dimensions in mm				



### **Suggested Pad Layout**

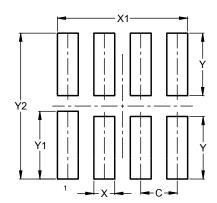
Please see http://www.diodes.com/package-outlines.html for the latest version.

#### X2-DFN1210-8



Dimensions	Value (in mm)
С	0.300
G	0.150
Х	0.150
X1	1.050
Υ	0.500
Y1	1.150

#### X2-DFN1410-8



Dimensions	Value
Dillielisions	(in mm)
С	0.350
Х	0.200
X1	1.250
Υ	0.600
Y1	0.650
Y2	1.400

#### **Mechanical Data**

#### X2-DFN1210-8

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu Nickel Palladium Gold, Solderable per MIL-STD-202, Method 208@4
- Weight: 0.002 grams (Approximate)

#### X2-DFN1410-8

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu Nickel Palladium Gold, Solderable per MIL-STD-202, Method 208 (4)
- Weight: 0.002 grams (Approximate)



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